Electronic Structure Properties of UO2 as a Mott Insulator

Samira Sheykhi, Mahmoud Payami

Abstract
In this work using the density functional theory (DFT), we have studied the structural, electronic and magnetic properties of uranium dioxide with antiferromagnetic 1k-, 2k-, and 3k-order structures. Ordinary approximations in DFT, such as the local density approximation (LDA) or generalized gradient approximation (GGA), usually predict incorrect metallic behaviors for this strongly correlated electron system. Using Hubbard term correction for f-electrons, LDA+U method, as well as using the screened Heyd-Scuseria-Ernzerhof (HSE) hybrid functional for the exchange-correlation (XC), we have obtained the correct ground-state behavior as an insulator, with band gaps in good agreement with experiment.

Keywords: Mott insulator; Antiferromagnetic; Uranium dioxide; Density functional theory; Hybrid functional

1. Introduction
Urania (UO2) is one of the most common fuels used in nuclear power reactors, and understanding its properties, both experimentally [1] and theoretically [2, 3, 4, 5], has been one of the hot topics of research activity for several years. The crystal structure of urania has been experimentally determined to be an antiferromagnetic 3k-order Mott insulator at temperatures below 30 °K, in which the uranium atoms are located in an fcc lattice with a=b=c=5.47 Å, and the oxygen atoms are located at positions with symmetry Pa3 [6]. In Fig 1(a)-(c), we have shown the antiferromagnetic 1k-, 2k-, and 3k-order structures.

DFT is one of the most powerful methods for calculation of electronic structure properties of materials [7, 8]. Application of ordinary DFT, using LDA or GGA for the exchange-correlation functional, incorrectly predicts a metal behavior (see Fig 2) for urania, while it is known as a Mott insulator solid. This behavior is due to the localized “d” and “f” electrons that in ordinary DFT
Figure 1: UO$_2$ in (a) 1k-order, (b) 2k-order, and (c) 3k-order antiferromagnetic structures.

calculations are accounted as nearly delocalized ones which is appropriate for s-p bonded solid materials. One of the methods to rectify this deficiency is the use of DFT+U method \cite{9} in which a Hubbard term for the localized “f” electrons is added to the Hamiltonian, and this correction leads to an opening of a gap, leading to an insulating properties. The method is somewhat tricky and to obtain the true ground state, one has to avoid metastable states \cite{2}. Another method, which is rather new and more appropriate, is using the screened HSE hybrid functional \cite{10} which partially uses the exact exchange operator. Using this orbital-dependent functional is computationally very expensive and the newly formulated Adaptively Compressed Exchange (ACE) Operator \cite{11} significantly reduces the computational efforts while keeping its accuracy. In this work, we have used LDA and LDA+U methods for 1k, 2k, and 3k antiferromagnetic configurations. The HSE-ACE method is applied only to the 1k-order. All LDA+U results as well as the HSE-ACE, correctly predict insulating behaviors for UO$_2$.

2. Calculation methods

All calculations are based on DFT and the solution of the Kohn-Sham equations \cite{8} using the Quantum-ESPRESSO code package \cite{12}. For the atoms U and O, we have used the pseudopotentials U.pz-mt-fhi.UPF and O.pz-mt-fhi.UPF which are available at http://www.quantum-espresso.org. By convergency tests, the kinetic energy cutoffs for the plane-wave bases are chosen as 40 and 160 Ry for the wave functions and charge density, respectively. In HSE calculations, the plane-wave cutoff for expansion of the Fock exchange operator is taken as 80 Ry. For the Brillouin-zone integrations, a $4 \times 4 \times 4$ grid with a shift were used. In LDA+U calculations, we have used the values 4.5 and 0.54 eV for U and J parameters, respectively as determined by other works \cite{13,14}. All geometries are fully optimized for pressures on unit cells to within 1kPa, and forces on atoms to within 1mRy/a.u.
3. Results and Discussions

The LDA calculations for all UO$_2$ antiferromagnetic structures lead to metallic states, as are shown by density-of-states (DOS) plots in Figs. 2(e)-(g). The LDA+U calculations for the 1k-order configuration, led to a small deformation in c-axis corresponding to a tetragonal structure with a=b=5.49, and c=5.44 Å, with a gap of 1.5 eV.

As to 2k-order configuration, locating the ground-state in LDA+U was somewhat tricky in that one should avoid metastable states, and the true ground state was achieved by some modifications in the occupation matrix. The results show a similar deformation as in 1k-order but with a=b=5.50, and c=5.49 Å, with 1.9 eV gap.

For 3k-order, the optimization of the structure maintained the cubic structure with a=b=c=5.50 Å, but with a small Jahn-Teller distortion for the oxygen atoms (0.0153 Å in <111> direction) in good agreement with experiment. The energy gap was found to be 1.7 eV, in good agreement with the experiment (2.1 eV). Here, locating the true ground state was also tricky as in 2k case.

Finally, the HSE-ACE calculations for the 1k-order led to a similar tetragonal structure with a=b=5.53, and c=5.54 Å. In this calculation, the c-axis is slightly elongated in contrast to our LDA+U results. It has been shown that the $c < a$ or $c > a$ behavior depends on the choice of Hubbard U and J values [15]. This calculation resulted in a gap of 2.02 eV which is quite in good agreement with experiment as compared with the LDA+U results. The DOS plots for LDA+U and HSE-ACE are shown in Figs. 2(a)-(d), respectively. It should be mentioned that the lower band-gap shown in Fig. 2(d) compared to those of
LDA+U (whereas it should be higher) is due to low-density k-mesh for producing
the DOS-plot. We have presented the HSE-ACE plot only to show that HSE
correctly reproduce the insulating behavior; the band gap is simply read off
from the calculated Kohn-Sham eigenvalues.

4. Conclusions

LDA or GGA calculations for UO₂ lead to an incorrect metallic behavior.
This is corrected using the LDA+U method and using HSE hybrid functional.
The 1k- and 2k-order antiferromagnetic structures lead to a small deformation in
the c-axis, while the 3k-order LDA+U preserves the cubic symmetry for U atoms
even though the O atoms are slightly distorted along the <111> direction.
All LDA+U and HSE calculations led to correct insulating behaviors. More
interestingly, the gap reproduced by HSE calculation is in a very good agreement
with experimental value.

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